TLP3548,TLP3548F

1. Applications

- Mechanical relay replacements
- Factory Automation (FA)
- Programmable Logic Controllers (PLCs)
- Measuring Instruments
- ATE (Automatic Test Equipment)

2. General

The TLP3548 and TLP3548F photorelay consist of a photo MOSFET optically coupled to an infrared LED. It is housed in a 8-pin DIP package. The low ON-state resistance and the high permissible ON-state current of the TLP3548 and TLP3548F make it suitable for power line control applications.

3. Features

- (1) Normally opened (1-Form-A)
- (2) OFF-state output terminal voltage: 400 V (min)
- (3) Trigger LED current: 1 mA (max)
- (4) ON-state current: 0.4 A (max) (A connection)
- (5) ON-state resistance: 5Ω (max) (A connection)
- (6) Isolation voltage: 2500 Vrms (min)
- (7) Safety standards

UL-recognized: UL 1577, File No.E67349

cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

UL-recognized: UL 508, File No.E499232 (Note 1)

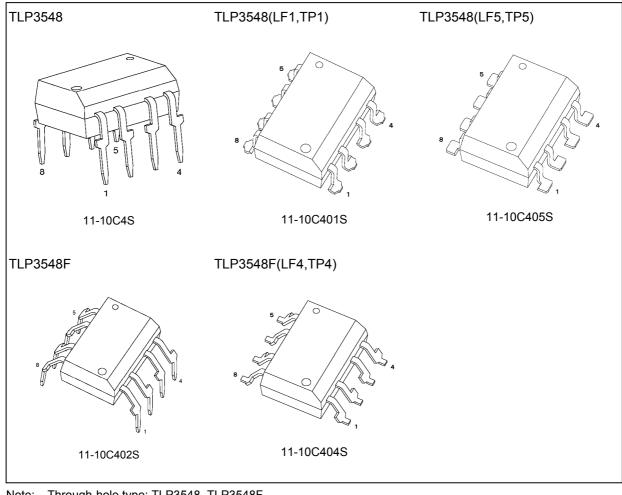
VDE-approved: EN 60747-5-5 (Note 2)

Note 1: Please refer Absolute Maximum Ratings (UL-recognized UL 508) for UL 508 products. Note 2: When a VDE approved type is needed, please designate the **Option (D4)**.

4. Mechanical Parameters

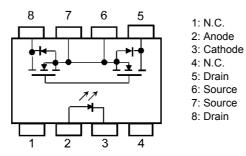
Characteristics	7.62-mm Pitch TLP3548	10.16-mm Pitch TLP3548F	Unit
Creepage distances	7.0 (min)	8.0 (min)	mm
Clearance distances	7.0 (min)	8.0 (min)	
Internal isolation thickness	0.4 (min)	0.4 (min)	

5. Packaging (Note)

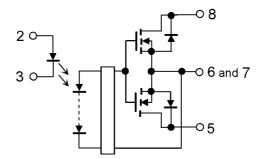


Note: Through-hole type: TLP3548, TLP3548F Lead forming option: (LF1), (LF4), (LF5) Taping option: (TP1), (TP4), (TP5)

6. Pin Assignment



7. Internal Circuit



8. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25 \degree$ C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		30	mA
	Input forward current derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_F / \Delta T_a$		-0.3	mA/°C
	Input forward current (pulsed)	(100 μ s pulse, 100 pps)	I _{FP}		1	A
	Input reverse voltage		V _R		5	V
	Input power dissipation		PD		50	mW
	Input power dissipation derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta P_D / \Delta T_a$		-0.5	mW/°C
	Junction temperature		Тj		125	°C
Detector	OFF-state output terminal voltage		V _{OFF}		400	V
	ON-state current (A connection)		I _{ON}	(Note 1)	0.4	A
	ON-state current (B connection)				0.4	
	ON-state current (C connection)		I _{ON}		0.8	
	ON-state current derating (A connection)	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_{ON} / \Delta T_a$	(Note 1)	-4.0	mA/°C
	ON-state current derating (B connection)	$(T_a \ge 25 \ ^\circ C)$			-4.0	
	ON-state current derating (C connection)	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_{ON} / \Delta T_a$		-8.0	
	ON-state current (pulsed)	(t = 100 ms, duty = 1/10)	I _{ONP}		1.2	A
	Output power dissipation		Po		750	mW
	Output power dissipation derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta P_0 / \Delta T_a$		-7.5	mW/°C
	Junction temperature		Tj		125	°C
Common	Storage temperature		T _{stg}		-55 to 125	°C
	Operating temperature		T _{opr}		-40 to 85	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	AC, 60 s, R.H. ≤ 60 %	BVS	(Note 2)	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: For an application circuit example, see Chapter 16.2.

Note 2: This device is considered as a two-terminal device: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

9. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V _{DD}		_	—	320	V
Input forward current	١ _F		_	2	25	mA
ON-state current (A connection)	I _{ON}		_	_	0.4	А
Operating temperature	T _{opr}		-40		85	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

10. Absolute Maximum Ratings (UL-recognized: UL 508) (Note) (Unless otherwise specified, $T_a = 25$ °C)

	Characteristics	3	Symbol	Note	Rating	Unit
LED	Input forward current		I _F		30	mA
	Input forward current derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_F / \Delta T_a$		-0.3	mA/°C
	Input forward current (pulsed)	(100 µs pulse, 100 pps)	I _{FP}		1	A
	Input reverse voltage		V _R		5	V
	Input power dissipation		PD		50	mW
	Input power dissipation derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta P_D / \Delta T_a$		-0.5	mW/°C
	Junction temperature		Tj		105	°C
Detector	OFF-state output terminal voltage		V _{OFF}		400	V
	ON-state current (A connection)		I _{ON}	(Note 1)	0.4	A
	ON-state current (B connection)				0.4	
	ON-state current (C connection)				0.8	
	ON-state current derating (A connection)	$(T_a \ge 25 \ ^\circ C)$	$\Delta I_{ON} / \Delta T_a$	(Note 1)	-4.0	mA/°C
	ON-state current derating (B connection)	$(T_a \ge 25 \ ^\circ C)$			-4.0	
	ON-state current derating (C connection)	$(T_a \ge 25 \ ^\circ C)$			-8.0	
	ON-state current (pulsed)	(t = 100 ms, duty = 1/10)	I _{ONP}		1.2	A
	Output power dissipation		Po		750	mW
	Output power dissipation derating	$(T_a \ge 25 \ ^\circ C)$	$\Delta P_0 / \Delta T_a$		-7.5	mW/°C
	Junction temperature		Tj		105	°C
Common	Storage temperature		T _{stg}		-55 to 125	°C
	Case temperature		T _c		105	°C
	Operating temperature		T _{opr}		-40 to 85	°C
	Lead soldering temperature	(10 s)	T _{sol}		260	°C
	Isolation voltage	(AC, 60 s, R.H. \leq 60 %)	BVS	(Note 2)	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: For an application circuit example, see Chapter 16.2.

Note 2: This device is considered as a two-terminal device: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

11. Recommended Operating Conditions (UL-recognized: UL 508) (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V _{DD}		_	—	320	V
Input forward current	١ _F	(Note 1)	_	2	19.5	mA
ON-state current(A connection)	I _{ON}	(Note 1)	_	_	0.26	А
Operating temperature	T _{opr}		-20	_	85	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note 1: The above recommended operating conditions are at $T_a = 60$ °C.

However, within the derating range of the characteristic curves of " $I_F - T_a$ ", " $I_{ON} - T_a$ ", it can be used up to 85 °C.

12. Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V _F		I _F = 10 mA	1.50	1.64	1.80	V
	Input reverse current	I _R		V _R = 5 V	_		10	μA
	Input capacitance	Ct		V = 0 V, f = 1 MHz	_	70	_	pF
Detector	OFF-state current	I _{OFF}		V _{OFF} = 400 V	_	0.001	1	μA
	Output capacitance	C _{OFF}		V = 0 V, f = 1 MHz		410	_	pF

13. Coupled Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		I _{ON} = 0.4 A	_	0.2	1.0	mA
Return LED current	I _{FC}		I _{OFF} = 1 μA	0.01	0.19	_	
ON-state resistance (A connection)	R _{ON}	(Note 1)	I _{ON} = 0.4 A, I _F = 2 mA, t < 1 s	_	3.0	5.0	Ω
ON-state resistance (B connection)			I _{ON} = 0.4 A, I _F = 2 mA, t < 1 s	_	_	2.5	
ON-state resistance (C connection)			I _{ON} = 0.8 A, I _F = 2 mA, t < 1 s		_	1.3	

Note 1: For an application circuit example, see Chapter 16.2.

14. Isolation Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	CS	(Note 1)	V _S = 0 V, f = 1 MHz		0.8	—	pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. $\leq 60~\%$	5×10 ¹⁰	1014	—	Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	2500	_	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

15. Switching Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}		See Fig. 15.1.		0.22	1.0	ms
Turn-off time	t _{OFF}		R_{L} = 200 Ω, V_{DD} = 20 V, I_{F} = 5 mA	_	0.08	1.0	

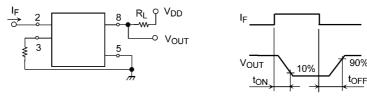
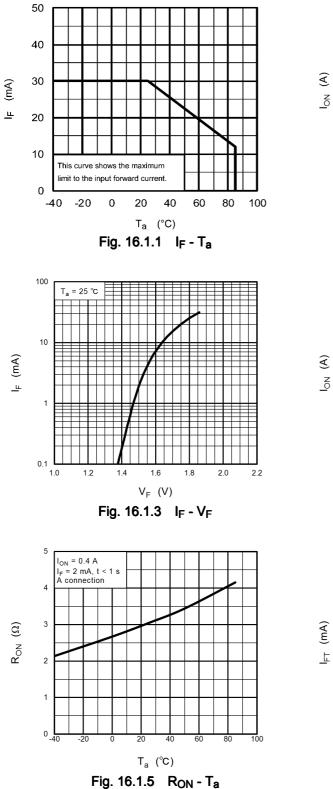


Fig. 15.1 Switching Time Test Circuit and Waveform

16. Characteristics Curves and Circuit Connections

16.1. Characteristics Curves (Note)



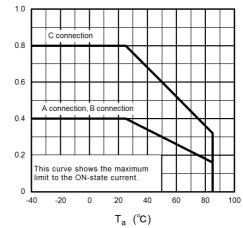
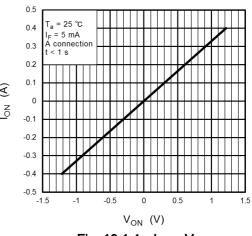
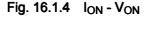
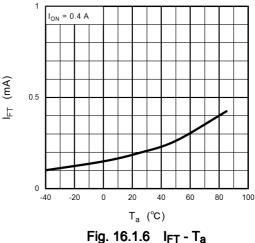
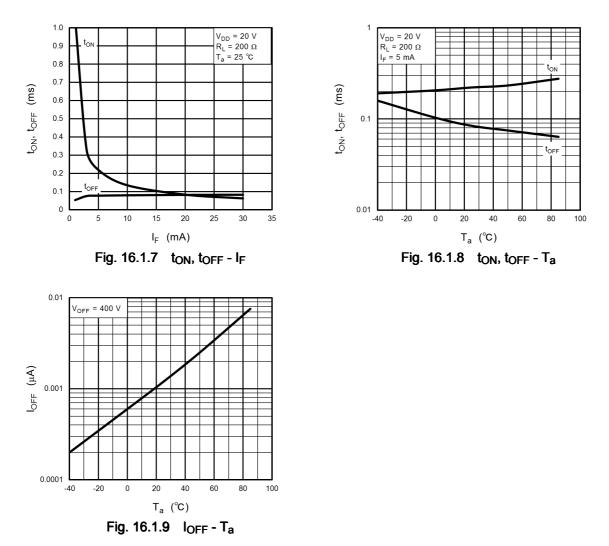


Fig. 16.1.2 I_{ON} - T_a









Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

16.2. Circuit Connections

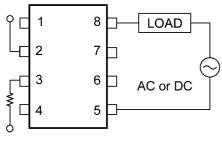


Fig. 16.2.1 A Connection

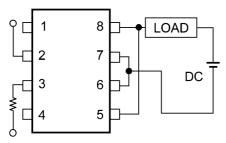
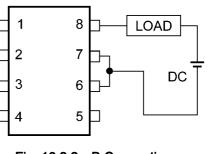


Fig. 16.2.3 C Connection





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Fig. 16.2.2 B Connection

17. Soldering and Storage

17.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

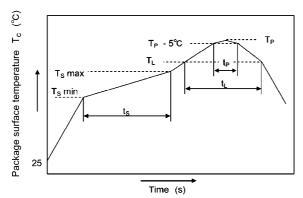
• When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	S
Ramp-up rate $(T_L \text{ to } T_P)$			3	°C/s
Liquidus temperature	TL	2	°C	
Time above T_L	tL	60	150	s
Peak temperature	Τ _Ρ		260	°C
Time during which T_c is between (T _P – 5) and T_P	t₽		30	s
Ramp-down rate $(T_P \text{ to } T_L)$			6	°C/s

Fig. 17.1.1 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

When using soldering flow

Preheat the device at a temperature of 150 $^{\circ}$ C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 $^{\circ}$ C within 10 seconds is recommended.

Flow soldering must be performed once.

When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

17.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

18. Land Pattern Dimensions (for reference only)

(Unit: mm)

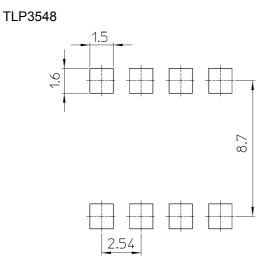


Fig. 18.1 Lead forming and taping option (LF1), (TP1), (LF5), (TP5)

19. Marking

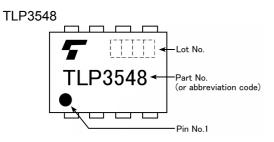
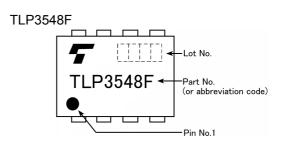


Fig. 18.2 Lead forming and taping option (LF4), (TP4)



20. EN 60747-5-5 Option (D4) Specification

- Part number: TLP3548 (Note)
- The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN 60747.

Example: TLP3548(D4,TP1,F

D4: EN 60747 option TP1: Tape type F: [[G]]/RoHS COMPATIBLE (Note 1)

Note: Use TOSHIBA standard type number for safety standard application.

e.g., TLP3548(D4,TP1,F \rightarrow TLP3548

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Description	Symbol	Rating	Unit	
Application classification				
for rated mains voltage ≤ 300 Vrms for rated mains voltage ≤ 600 Vrms			I-IV I-III	
Climatic classification			40 / 85 / 21	_
Pollution degree			2	
••••••	TLPxxx type		890	.,,
Maximum operating insulation voltage	TLPxxxF type	VIORM	1140	Vpk
Input to output test voltage, Method A	TLPxxx type	- Vpr	1424	
Vpr = 1.6 × VIORM, type and sample test tp = 10 s, partial discharge < 5 pC	TLPxxxF type		1824	Vpk
Input to output test voltage, Method B	TLPxxx type		1670	Vpk
Vpr = 1.875 × VIORM, 100% production test tp = 1 s, partial discharge < 5 pC	TLPxxxF type	- Vpr	2140	
Highest permissible Overvoltage	TLPxxx type	- Vtr	6000	Vpk
(transient overvoltage, tpr = 60 s)	TLPxxxF type	VIR	0000	vpk
Safety limiting values (max. permissible ratings in case also refer to thermal derating c				
current (input current IF, Pso = 0) power (output or total power dissipation) temperature	lsi Pso Ts	400 700 150	mA mW °C	
Insulation resistance VIO = 500 V, Ta = 25 °C VIO = 500 V, Ta = 100 °C VIO = 500 V, Ta = 100 °C VIO = 500 V, Ta = Ts VIO = 500 V, Ta = Ts	Rsi	≥ 10 ¹² ≥ 10 ¹¹ ≥ 10 ⁹	Ω	

Fig. 20.1 EN 60747 Insulation Characteristics

TLP3548

Fig. 20.3

Insulation Related Parameters	Symbol	TLP3548	TLP3548F				
Minimum creepage distance	Cr	7.0 mm	8.0 mm				
Minimum clearance	CI	7.0 mm	8.0 mm				
Minimum insulation thickness	ti	0.4 mm	0.4 mm				
Comparative tracking index	CTI	175	175				

 Table
 Insulation Related Specifications (Note)

Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e.g., at a standard distance between soldering eye centers of 7.5 mm). If this is not permissible, the user shall take suitable measures.

Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.



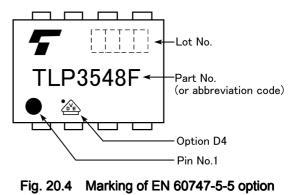
Fig. 20.2 Marking on Packing for EN 60747

TLP3548 Option D4 Pin No.1

(VDE-approved) (Note)

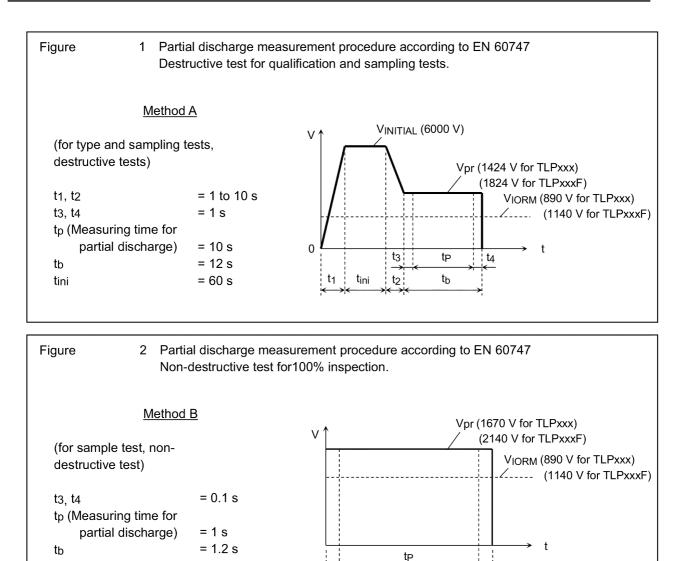
Marking of EN 60747-5-5 option

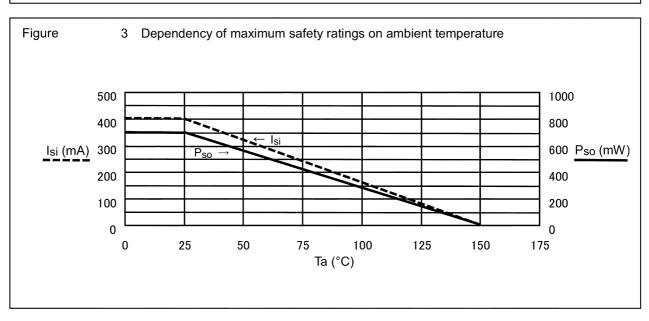
TLP3548F



(VDE-approved) (Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN 60747.





t3

tb

t4



21. Ordering Information

When placing an order, please specify the part number, tape type and quantity as shown in the following example.

Example) TLP3548(TP1,F 1500 pcs

Part number: TLP3548 Tape type: TP1 [[G]]/RoHS COMPATIBLE: F **(Note)** Quantity (must be a multiple of 1500): 1500 pcs

Note: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility. RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

22. Ordering Information (Example of Item Name)

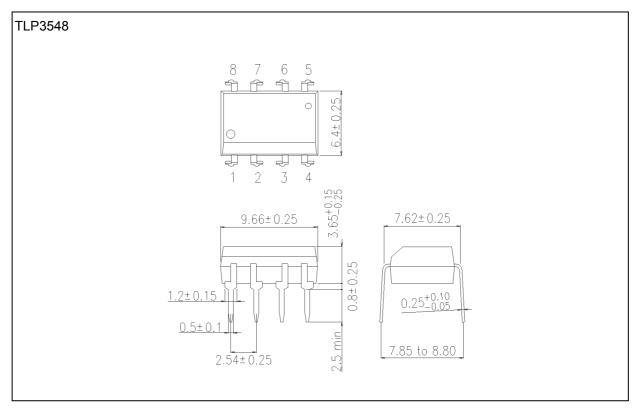
Item Name	Packaging (Note 1)	VDE Option	Packing (MOQ)
TLP3548(F	тн		Magazine (50 pcs)
TLP3548(LF1,F	LF1		Magazine (50 pcs)
TLP3548(LF5,F	LF5		Magazine (50 pcs)
TLP3548(TP1,F	LF1		Tape and reel (1500 pcs)
TLP3548(TP5,F	LF5		Tape and reel (1500 pcs)
TLP3548F(F	TH, Wide forming		Magazine (50 pcs)
TLP3548F(LF4,F	LF4, Wide forming		Magazine (50 pcs)
TLP3548F(TP4,F	LF4, Wide forming		Tape and reel (1000 pcs)
TLP3548(D4,F	ТН	EN 60747-5-5	Magazine (50 pcs)
TLP3548(D4,LF1,F	LF1	EN 60747-5-5	Magazine (50 pcs)
TLP3548(D4,LF5,F	LF5	EN 60747-5-5	Magazine (50 pcs)
TLP3548(D4,TP1,F	LF1	EN 60747-5-5	Tape and reel (1500 pcs)
TLP3548(D4,TP5,F	LF5	EN 60747-5-5	Tape and reel (1500 pcs)
TLP3548F(D4,F	TH, Wide forming	EN 60747-5-5	Magazine (50 pcs)
TLP3548F(D4LF4,F	LF4, Wide forming	EN 60747-5-5	Magazine (50 pcs)
TLP3548F(D4TP4,F	LF4, Wide forming	EN 60747-5-5	Tape and reel (1000 pcs)

Note 1: TH: Through-hole, LF/TP: Lead forming for surface mount

Package Dimensions

TLP3548,TLP3548F

Unit: mm



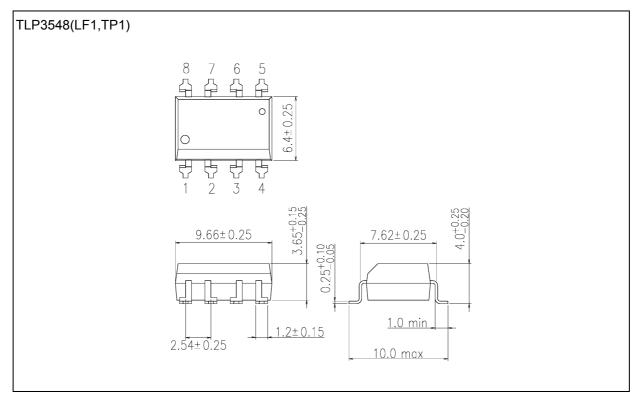
Weight: 0.54 g (typ.)

	Package Name(s)
TOSHIBA: 11-10C4S	

TLP3548,TLP3548F

Package Dimensions

Unit: mm



Weight: 0.53 g (typ.)

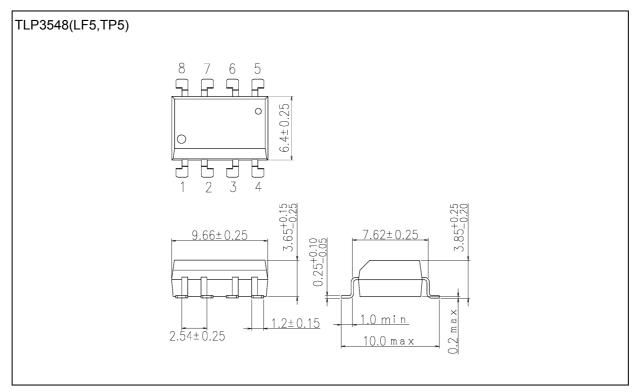
	Package Name(s)
TOSHIBA: 11-10C401S	



TLP3548,TLP3548F

Package Dimensions

Unit: mm



Weight: 0.53 g (typ.)

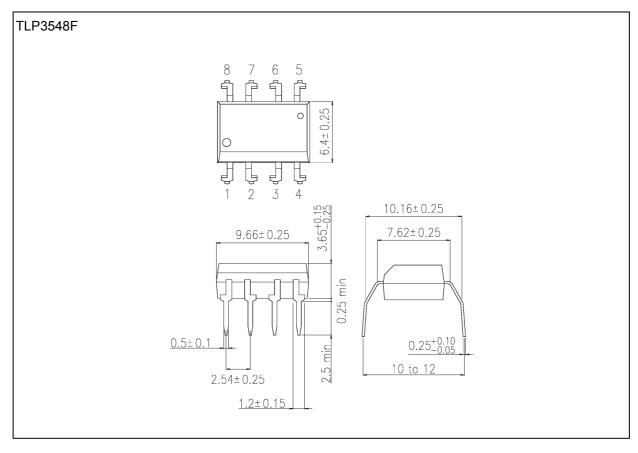
Package	Name(s)
· aonago	

TOSHIBA: 11-10C405S

Package Dimensions

TLP3548,TLP3548F

Unit: mm



Weight: 0.54 g (typ.)

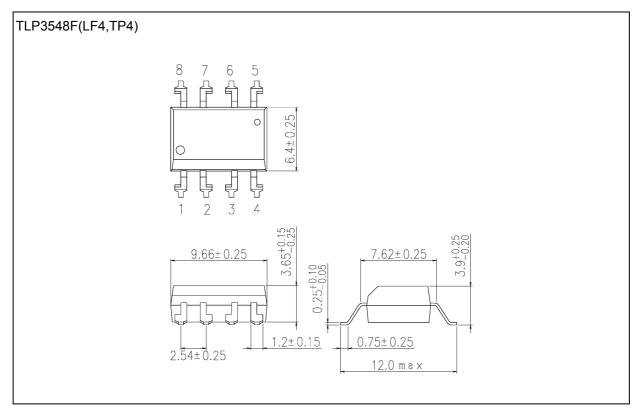
Package Name(s)
TOSHIBA: 11-10C402S



TLP3548,TLP3548F

Package Dimensions

Unit: mm



Weight: 0.53 g (typ.)

Package Name(s)	
TOSHIBA: 11-10C404S	

RESTRICTIONS ON PRODUCT USE

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